



DMP6050SFG

60V P-CHANNEL ENHANCEMENT MODE MOSFET POWERDI®

Product Summary

V _{(BR)DSS}	R _{DS(ON)} max	I _D max T _A = +25°C
	50m $Ω @ VGS = -10V$	-4.8A
-60V	70mΩ @ V _{GS} = -4.5V	-4.1A

Description and Applications

This MOSFET has been designed to minimize the on-state resistance $(R_{DS(ON)})$ and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Backlighting
- Power Management Functions
- DC-DC Converters

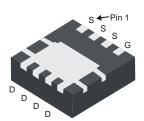
Features and Benefits

- Low R_{DS(ON)} Ensures On State Losses Are Minimized
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products
- Occupies Just 33% of The Board Area Occupied by SO-8 Enabling Smaller End Product
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: POWERDI[®]3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.072 grams (Approximate)

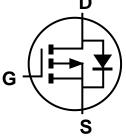
POWERDI®3333-8



Bottom View



Top View



Equivalent Circuit

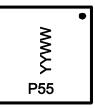
Ordering Information (Note 4)

Part Number	Case	Packaging
DMP6050SFG-7	POWERDI [®] 3333-8	2000/Tape & Reel
DMP6050SFG-13	POWERDI [®] 3333-8	3000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



P55= Product Type Marking Code YYWW = Date Code Marking YY = Last Digit of Year (ex: 14 = 2014) WW = Week Code (01 to 53)



Maximum Ratings @T_A = +25°C, unless otherwise specified.

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V_{DSS}	-60	V		
Gate-Source Voltage	V_{GSS}	±20	V		
Continuous Durin Compant (Nata C) V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	-4.8 -3.9	А
Continuous Drain Current (Note 6) V _{GS} = -10V	t<10s	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	-6.0 -4.8	А
Pulsed Drain Current (10µs pulse, duty cycle = 1%)	I _{DM}	-32	Α		
Maximum Continuous Body Diode Forward Current (I _S	-2.8	Α		
Avalanche Current (Note 7) L = 0.1mH	I _{AS}	-24.8	А		
Repetitive Avalanche Energy (Note 7) L = 0.1mH	E _{AS}	30.8	mJ		

Thermal Characteristics $@T_A = +25^{\circ}C$, unless otherwise specified.

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		P _D	1.1	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady state		118	°C/W
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	$R_{\theta JA}$	78	
Total Power Dissipation (Note 6)		P _D	1.8	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady state	D.	71	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	$R_{\theta JA}$	46	
Thermal Resistance, Junction to Case (Note 6)	$R_{\theta JC}$	6.7		
Operating and Storage Temperature Range		$T_{J_i} T_{STG}$	-55 to +150	°C

Electrical Characteristics @T_A = +25°C, unless otherwise specified.

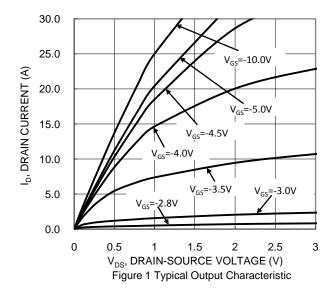
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage		-60	_	_	V	$V_{GS} = 0V, I_{D} = -250\mu A$	
Zero Gate Voltage Drain Current T _J = +25°C		_	_	-1	μΑ	$V_{DS} = -60V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(TH)}	-1.0		-3.0	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
Static Drain-Source On-Resistance	D	_	36	50	mΩ	$V_{GS} = -10V, I_D = -5A$	
Static Dialin-Source On-Resistance	R _{DS (ON)}	_	47	70	mΩ	$V_{GS} = -4.5V$, $I_D = -4A$	
Diode Forward Voltage	V_{SD}	_	-0.7	-1.2	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 9)						_	
Input Capacitance	Ciss	_	1293	_	pF	201/1/201/	
Output Capacitance	Coss	_	86.3	_	pF	$V_{DS} = -30V, V_{GS} = 0V,$ -f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	_	64.7		pF	1 = 1.0IVIDZ	
Gate Resistance	R_g	_	12		Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = -4.5V)	Q_g	_	11.9		nC		
Total Gate Charge (V _{GS} = -10V)	Q_{g}	_	24	_	nC	\/ 20\/ I 5A	
Gate-Source Charge	Qgs	_	3.6	_	nC	$V_{DS} = -30V, I_{D} = -5A$	
Gate-Drain Charge	Q _{qd}	_	5.7	_	nC	1	
Turn-On Delay Time	t _{D(ON)}	_	4.3	_	ns	$V_{GS} = -10V, V_{DS} = -30V,$ $R_G = 3\Omega, I_D = -5A$	
Turn-On Rise Time	t _R	_	6.3	_	ns		
Turn-Off Delay Time	t _{D(OFF)}	_	46.7	_	ns		
Turn-Off Fall Time	t _F	_	25.3	_	ns		
Body Diode Reverse Recovery Time	t _{RR}		13.6	_	ns	$I_F = -5A$, $di/dt = 100A/\mu s$	
Body Diode Reverse Recovery Charge	Q_{RR}	_	7.4	_	nC	$I_F = -5A$, $di/dt = 100A/\mu s$	

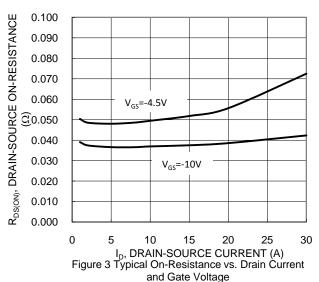
Notes

Downloaded from **Arrow.com**.

- 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
- 7. I_{AS} and E_{AS} rating are based on low frequency and duty cycles to keep $T_J = +25$ °C.
- 8. Short duration pulse test used to minimize self-heating effect.
- 9. Guaranteed by design. Not subject to product testing.







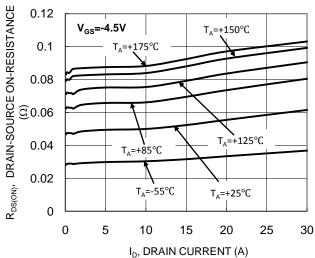


Figure 5 Typical On-Resistance vs. Drain Current and Temperature

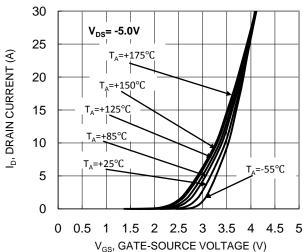


Figure 2 Typical Transfer Characteristic

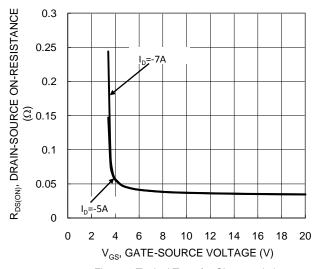


Figure 4 Typical Transfer Characteristic

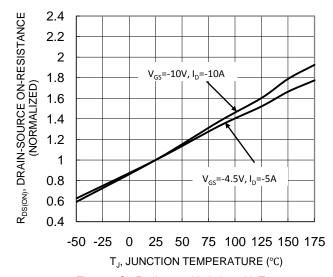


Figure 6 On-Resistance Variation with Temperature

 $\label{eq:powerpolicy} \mbox{POWERDI is a registered trademark of Diodes Incorporated.} \\ \mbox{DMP6050SFG}$



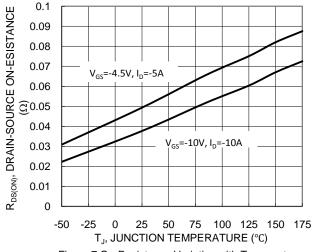
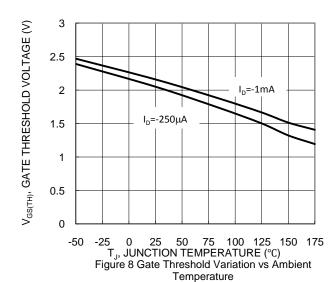


Figure 7 On-Resistance Variation with Temperature



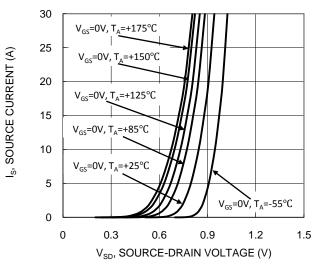
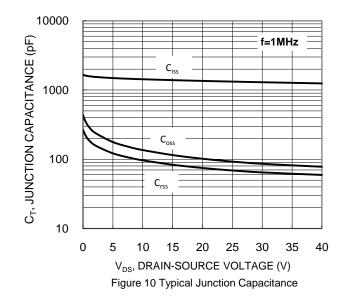
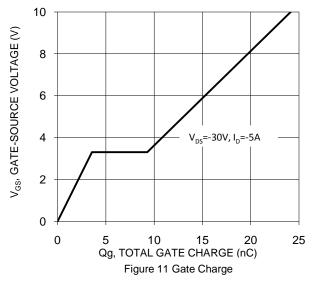
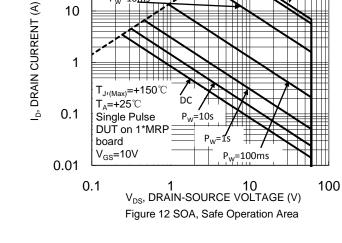


Figure 9 Diode Forward Voltage vs. Current





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100

10

1

R_{DS(ON)} Limited

T_J,_(Max)=+150°C T_A=+25℃



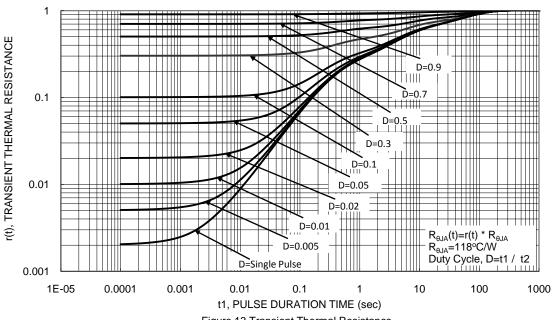
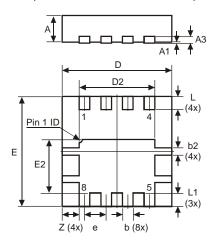


Figure 13 Transient Thermal Resistance

Package Outline Dimensions

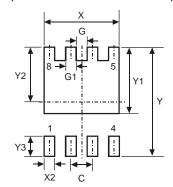
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



POWERDI 3333-8					
Dim	Min	Max	Тур		
D	3.25	3.35	3.30		
Е	3.25	3.35	3.30		
D2	2.22	2.32	2.27		
E2	1.56	1.66	1.61		
Α	0.75	0.85	0.80		
A1	0	0.05	0.02		
A3	_	_	0.203		
b	0.27	0.37	0.32		
b2	_	_	0.20		
L	0.35	0.45	0.40		
L1	_	_	0.39		
е	_	_	0.65		
Z	_	_	0.515		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)				
С	0.650				
G	0.230				
G1	0.420				
Υ	3.700				
Y1	2.250				
Y2	1.850				
Y3	0.700				
Х	2.370				
X2	0.420				



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